

N-channel 60 V, 2.6 mΩ logic level MOSFET in SOT78 27 February 2013 Product data sheet

1. General description

Logic level N-channel MOSFET in SOT78 using TrenchMOS technology. Product design and manufacture has been optimized for use in battery operated power tools.

2. Features and benefits

- High efficiency due to low switching & conduction losses
- Robust construction for demanding applications
- Logic level gate

3. Applications

- Battery-powered tools
- Load switching
- Motor control
- Uninterruptible power supplies

4. Quick reference data

Table 1. Qu	uick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	60	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	[1]	-	-	150	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	349	W
Static charac	cteristics		1				
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11		-	2	2.6	mΩ
Dynamic cha	aracteristics	1	1			1	
Q _{G(tot)}	total gate charge	V_{GS} = 10 V; I _D = 25 A; V _{DS} = 48 V;		-	223	-	nC
Q _{GD}	gate-drain charge	<u>Fig. 13; Fig. 14</u>		-	41.2	-	nC
Avalanche ru	uggedness	·	1		- 1	1	
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$\label{eq:ID} \begin{array}{l} I_D = 150 \text{ A}; \ V_{sup} \leq 60 \text{ V}; \ R_{GS} = 50 \ \Omega; \\ V_{GS} = 10 \text{ V}; \ T_{j(init)} = 25 \ ^\circ\text{C}; \ unclamped; \\ \hline Fig. \ 3 \end{array}$		-	-	521.7	mJ

[1] Continuous current is limited by package.

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5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	G	gate	mb	D			
2	D	drain	$2 \rightarrow 0$				
3	S	source	TO-220AB (SOT78)	G G H G H G H G H G H G H G H G H G H G			

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PSMN2R5-60PL	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN2R5-60PL	PSMN2R5-60PL

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	$T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}$		-	60	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	150	А
		T _{mb} = 100 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	150	А
I _{DM}	peak drain current	T_{mb} = 25 °C; pulsed; $t_p \le 10 \ \mu$ s; Fig. 4		-	1002	А

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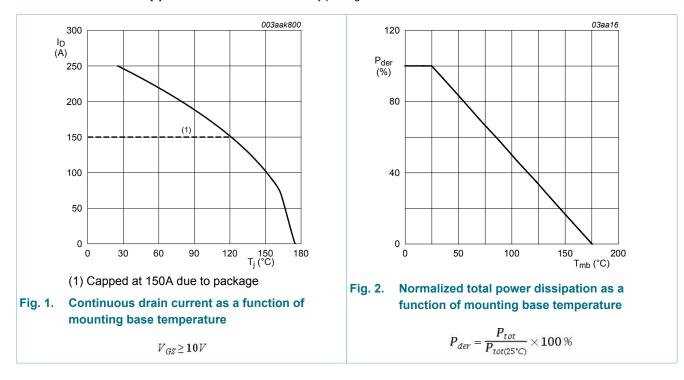
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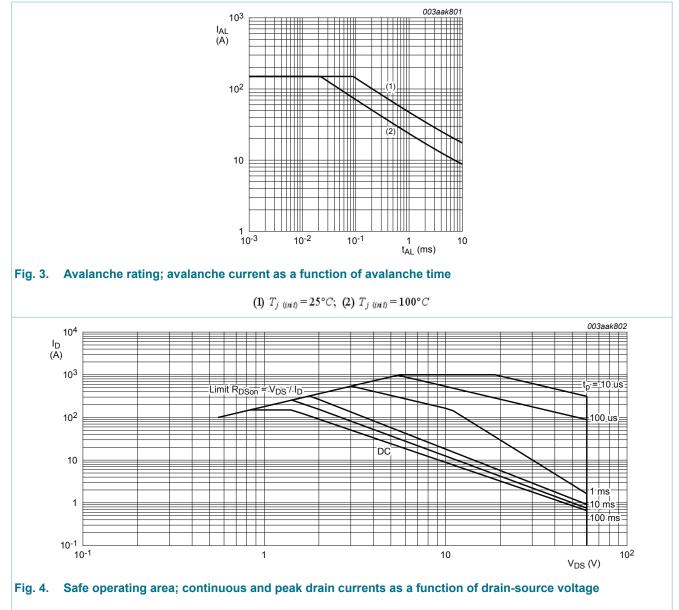
Symbol	Parameter	Conditions		Min	Max	Unit
-						
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	349	W
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-dra	in diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	150	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	1002	А
Avalanche	ruggedness					-
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	I_D = 150 A; V_{sup} ≤ 60 V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; Fig. 3		-	521.7	mJ



[1] Continuous current is limited by package.

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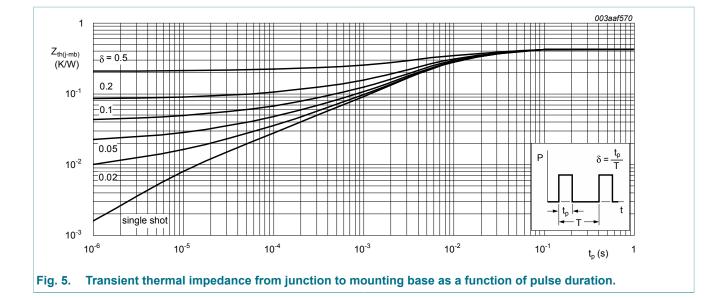
 $T_{mb} = 25^{\circ}C; \ I_{DM}$ is a single pulse

9. Thermal characteristics

Table 6. The	Fable 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	0.35	0.43	K/W	
R _{th(j-a)}	thermal resistance from junction to ambient	vertical in still air		-	60	-	K/W	

Table 6. Thermal characteristic

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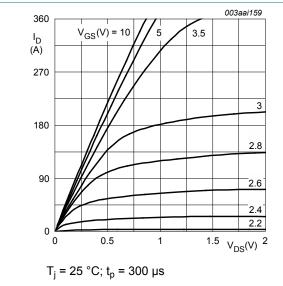


10. Characteristics

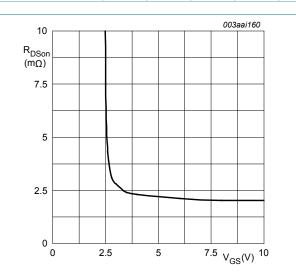
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · ·	I			
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	60	-	-	V
breakdown voltage	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	54	-	-	V
V _{GS(th)}	(th) gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 9; Fig. 10	1.4	1.7	2.1	V
	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 9	-	-	2.45	V	
	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 9	0.5	-	-	V	
I _{DSS} drain leakage curren	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	0.08	1	μA
		V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V_{GS} = 16 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11	-	2	2.6	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 11	-	2.3	3.15	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 12; Fig. 11	-	-	5.6	mΩ
R _G	gate resistance	f = 1 MHz	0.5	1	2	Ω

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic cl	haracteristics	· · · · · · · · · · · · · · · · · · ·	I			
Q _{G(tot)} total gate ch	total gate charge	I _D = 25 A; V _{DS} = 48 V; V _{GS} = 10 V; Fig. 13; Fig. 14	-	223	-	nC
		I _D = 25 A; V _{DS} = 48 V; V _{GS} = 5 V; Fig. 13; Fig. 14	-	120	-	nC
Q _{GS}	gate-source charge	I_D = 25 A; V_{DS} = 48 V; V_{GS} = 10 V;	-	25.6	-	nC
Q _{GD}	gate-drain charge	Fig. 13; Fig. 14	-	41.2	-	nC
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz; T _j = 25 °C; <u>Fig. 15</u>	-	11700	-	pF
C _{oss}	output capacitance		-	1025	-	pF
C _{rss}	reverse transfer capacitance		-	490	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 25 V; R _L = 1.8 Ω; V _{GS} = 5 V;	-	71	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$	-	119	-	ns
t _{d(off)}	turn-off delay time		-	224	-	ns
t _f	fall time		-	128	-	ns
Source-dra	in diode					
V _{SD}	source-drain voltage	I_{S} = 25 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 16</u>	-	0.77	1.2	V
t _{rr}	reverse recovery time	$I_{\rm S}$ = 20 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V;	-	53	-	ns
Q _r	recovered charge	V _{DS} = 25 V	-	98	-	nC







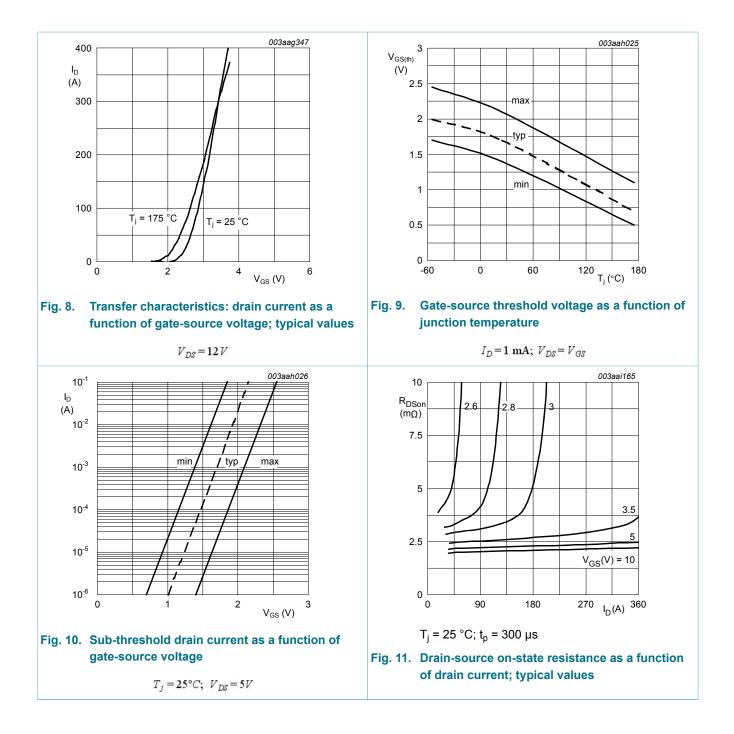


 $T_j = 25^{\circ}C; \ I_D = 25A$

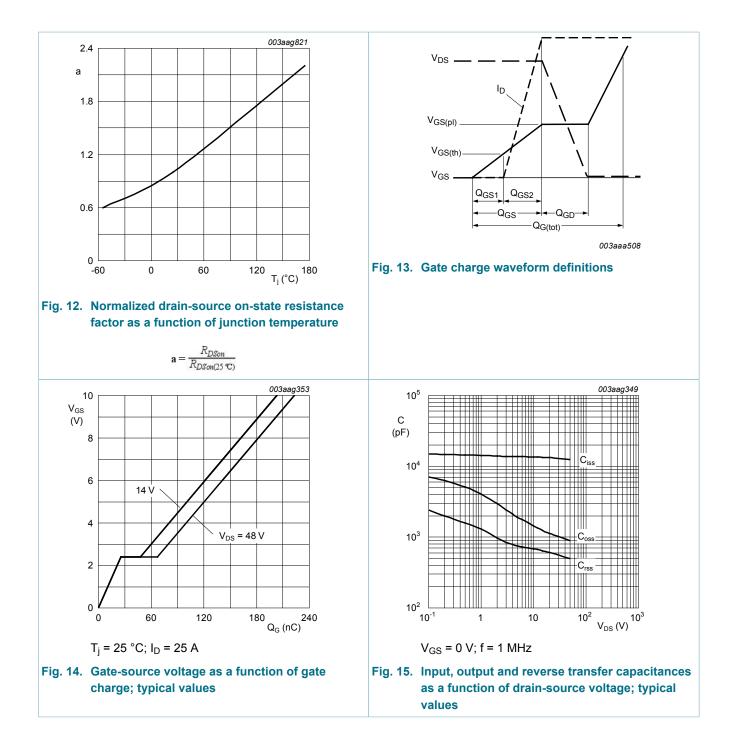
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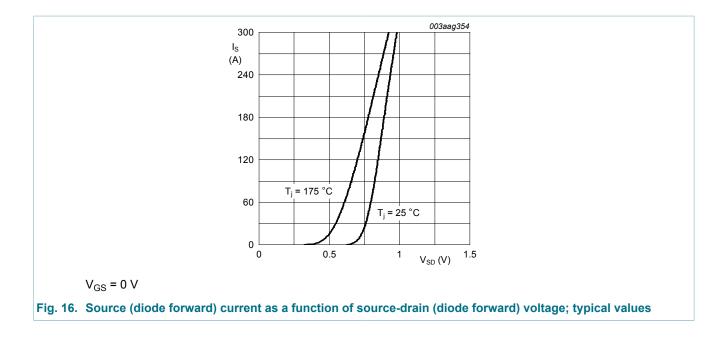
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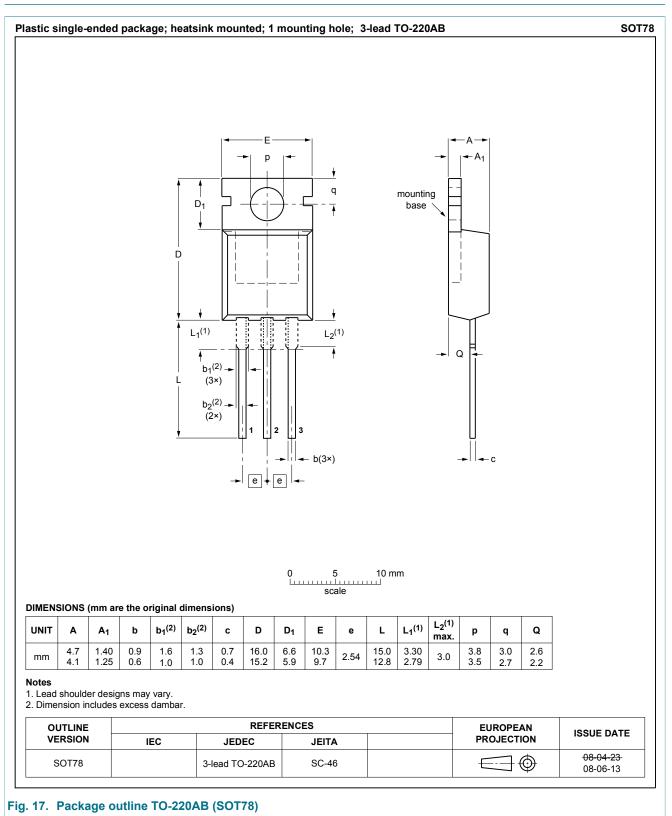
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11. Package outline



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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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N-channel 60 V, 2.6 mΩ logic level MOSFET in SOT78

13. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	
9	Thermal characteristics	4
10	Characteristics	5
11	Package outline	10
12	Legal information	11
12.1	Data sheet status	11
12.2	Definitions	11
12.3	Disclaimers	11
12.4	Trademarks	12

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